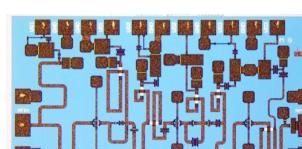
ALP302_0 17-21 GHz Low Noise Amplifier

Product Datasheet

NORTHROP GRUMMAN



X = 2.05mm Y = 1.15mm

Product Features

- RF frequency: 17.2 21.2 GHz
- Linear gain: 33 dB, typical
- Noise Figure: 0.8 1 dB, typical
- 0.1 um InP HEMT Process
- 3 mil substrate
- DC Power: ~ 50.4 mW
- Die Size: 2.35 sq.mm

Applications

- Point-to-Point Digital Radios
- Point-to-Multipoint Digital Radios
- SatCom Terminals

Product Description

The ALP302 is a K-band low noise amplifier MMIC fabricated in 0.1um InP HEMT. This part is ideally suited for satellite communications. The MMIC operates from 17.2 to 21.2 GHz and provides 31.5 dB of gain with a noise figure of 0.8 dB. The small die size allows for extremely compact packaging. To ensure rugged and reliable operation, HEMT devices are fully passivated. Both bond pad and backside metallization are Ti/Au, which is compatible with conventional die attach, thermocompression and thermosonic wire bonding assembly techniques.

Performance Characteristics (Ta = 25°C)

Specification	Min	Тур	Max	Unit
Frequency	17		21.2	GHz
Linear Gain	32	33	34	dB
Input Return Loss	-12.5		-2	dB
Output Return Loss	-33		-13.5	dB
Noise Figure		0.8	1	dB
Noise Figure (Ave)			1	dB
Vd1, Vd2, Vd3		1.4		V
Vg1, Vg2,Vg3		-0.5		V
ld1, ld2, ld3		12		mA

Export Information ECCN: 5A991.h HTS (Schedule B) code: 8542.33.0001

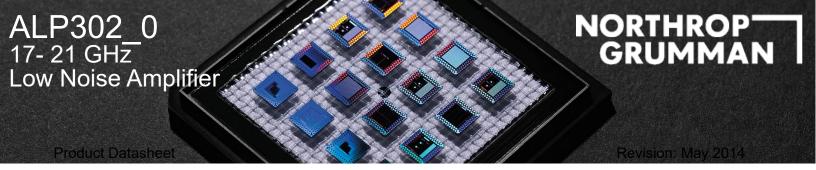
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Web: http://www.as.northropgrumman.com/mps

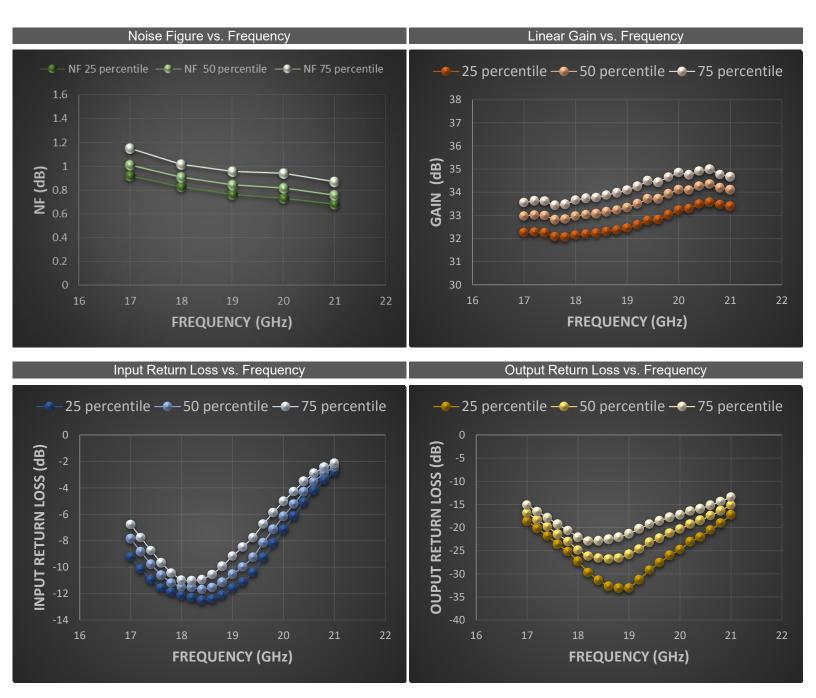
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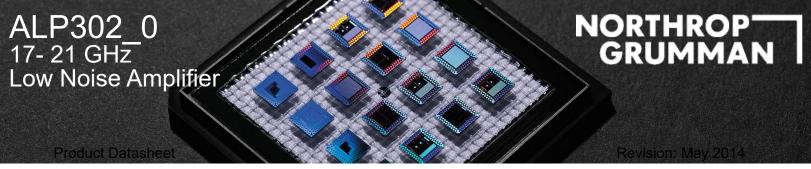
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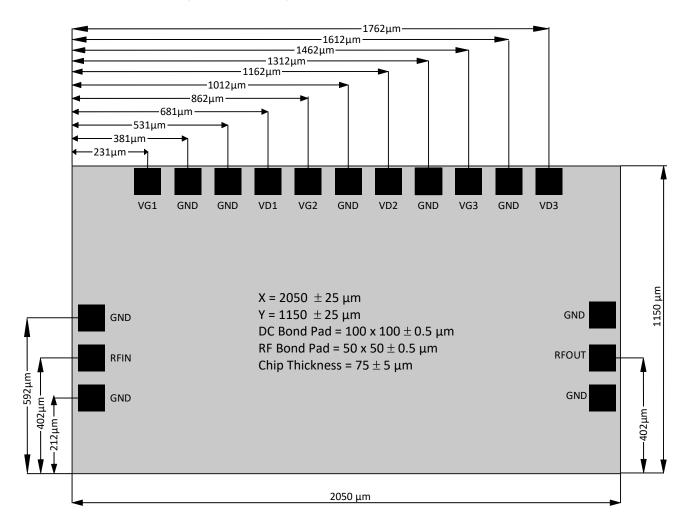
On-Wafer Measured Performance Characteristics (Typical Performance at 25°C) Vd1 = Vd2 = Vd3 = 1.4 V, Id1 = Id2 = Id3 = 12 mA



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Die Size and Bond Pad Locations (Not to Scale)



Recommended Assembly Notes

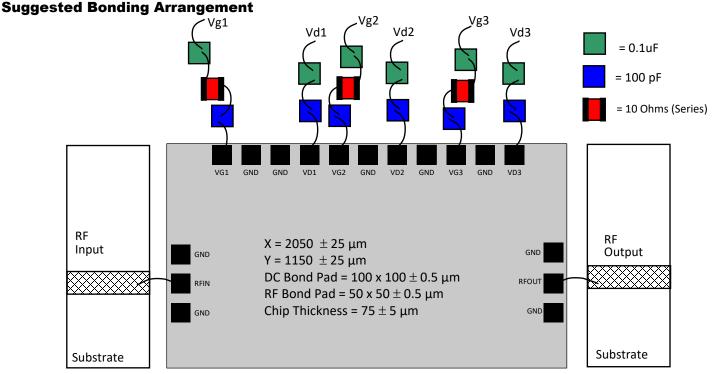
- 1. Bypass caps should be 100 pF (approximately) ceramic (single-layer) placed no farther than 30 mils from the amplifier.
- 2. Best performance obtained from use of <6 mil (long) by 1.5 by 0.5 mil ribbons on input and output.

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Biasing/De-Biasing Details:

Bias up sequence:

Set Vd1 & Vd2 & Vd3 = 0V

Set Vg1=Vg2 = Vg3 a to -0.3V and check to make sure there is no gate current. High gate current indicates leaky devices.

Increase Vd1 to +0.4V and check to make sure there are no oscillations.

If no oscillations are evident, increase Vd1 voltage to recommended value (1.4V).

Adjust Vg1 to realize the desired Id (12mA)

Repeat same steps for Vd2 & Vd3.

Set Vg2 to -0.3V and check to make sure there is no gate current .

Increase Vd2 to +0.4V and check to make sure there are no oscillations.

If no oscillations are evident, increase Vd2 voltage to recommended value (1.4V). Adjust Va2 to realize the desired Id (12mA)

Adjust Vg2 to realize the desired Id (12mA)

Bias down sequence:

Reduce Vg2 down to -0.6V Reduce Vg1=Vg1a down to -0.6V Lower Vd2 to 0V Lower Vd1 to 0V Lower Vg1 and Vg2 to 0V

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